6HP04CH

P-Channel Small Single MOSFET -60V, -370mA, 4.2Ω, Single CPH3



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Features

- 4V drive
- · Halogen free compliance
- · Protection diode in

Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain to Source Voltage	VDSS		-60	V
Gate to Source Voltage	V _{GSS}		±20	V
Drain Current (DC)	ID		-370	mA
Drain Current (Pulse)	IDP	PW≤10μs, duty cycle≤1%	-1480	mA
Allowable Power Dissipation	PD	When mounted on ceramic substrate (900mm ² ×0.8mm)	0.6	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

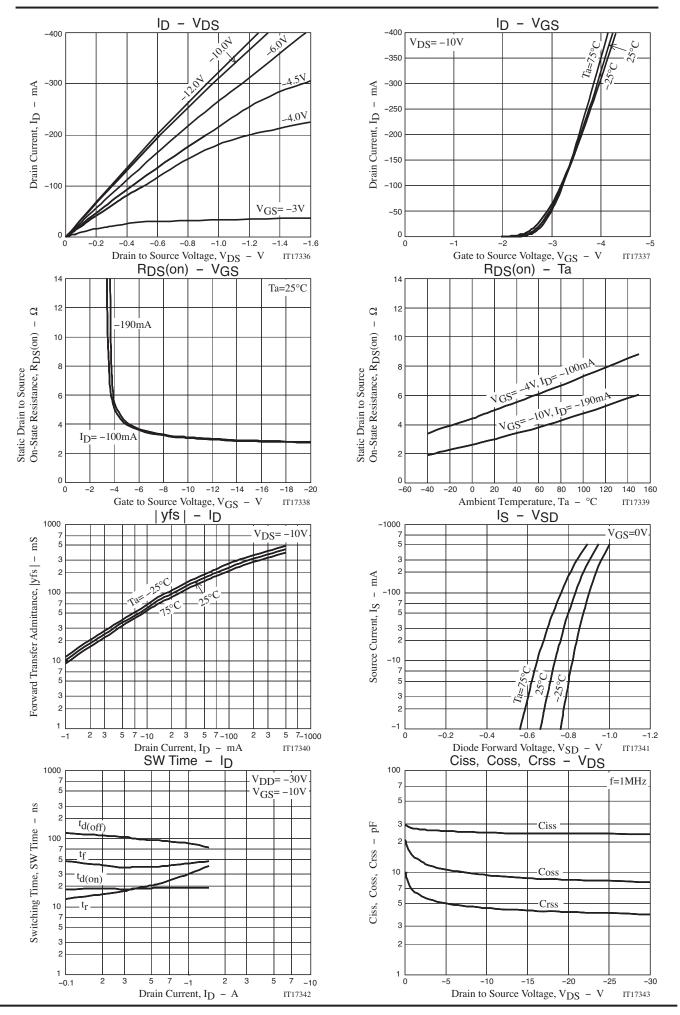
Electrical Characteristics at Ta=25°C

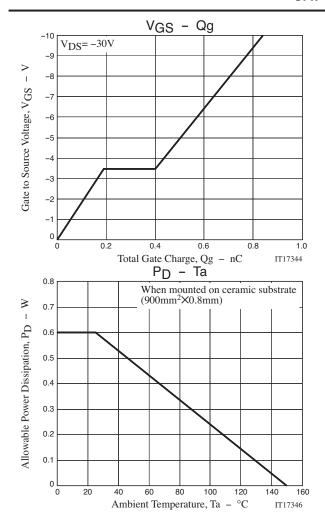
Parameter	Symbol	Conditions	Ratings			1.1
			min	typ	max	Unit
Drain to Source Breakdown Voltage	V(BR)DSS	I _D =-1mA, V _G S=0V	-60			V
Zero-Gate Voltage Drain Current	IDSS	V _D S=-60V, V _G S=0V			-1	μΑ
Gate to Source Leakage Current	IGSS	V _{GS} =±16V, V _{DS} =0V			±10	μΑ
Cutoff Voltage	V _{GS} (off)	V _{DS} =-10V, I _D =-100μA	-1.2		-2.6	V
Forward Transfer Admittance	yfs	V _{DS} =-10V, I _D =-190mA		310		mS
Static Drain to Source On-State Resistance	RDS(on)1	ID=-190mA, VGS=-10V		3.1	4.2	Ω
	R _{DS} (on)2	I _D =-100mA, V _G S=-4V		5.1	7.3	Ω
Input Capacitance	Ciss	V _{DS} =-20V, f=1MHz		24.1		pF
Output Capacitance	Coss			8.5		pF
Reverse Transfer Capacitance	Crss			4.1		pF
Turn-ON Delay Time	t _d (on)	See specified Test Circuit.		18.4		ns
Rise Time	t _r			15.2		ns
Turn-OFF Delay Time	t _d (off)			113		ns
Fall Time	tf			41		ns
Total Gate Charge	Qg	V _{DS} =-30V, V _{GS} =-10V, I _D =-370mA		0.84		nC
Gate to Source Charge	Qgs			0.19		nC
Gate to Drain "Miller" Charge	Qgd			0.21		nC
Diode Forward Voltage	VSD	IS=-370mA, VGS=0V		-0.92	-1.2	V

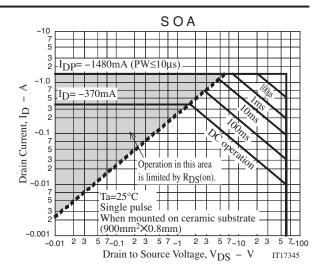
Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

ORDERING INFORMATION

See detailed ordering and shipping information on page 4 of this data sheet.





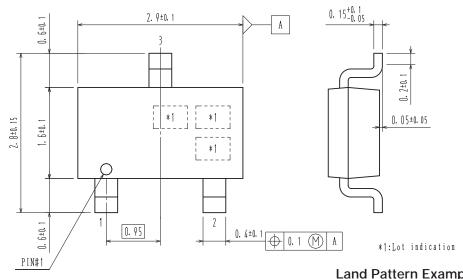


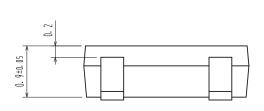
Package Dimensions 6HP04CH-TL-W

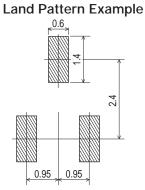
CPH3

CASE 318BA ISSUE O Unit: mm

- 1: Gate
- 2: Source
- 3: Drain



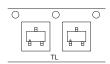




Ordering & Package Information

Device	Package	Shipping	memo	
6HP04CH-TL-W	CPH3, SC-59 SOT-23, TO-236	3,000 pcs. / reel	Pb-Free and Halogen Free	

Packing Type:TL

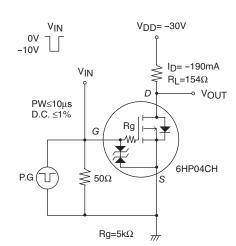




Electrical Connection

1

Switching Time Test Circuit



Note on usage: Since the 6HP04CH is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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